

## SOT-23 Digital transistors

### Features

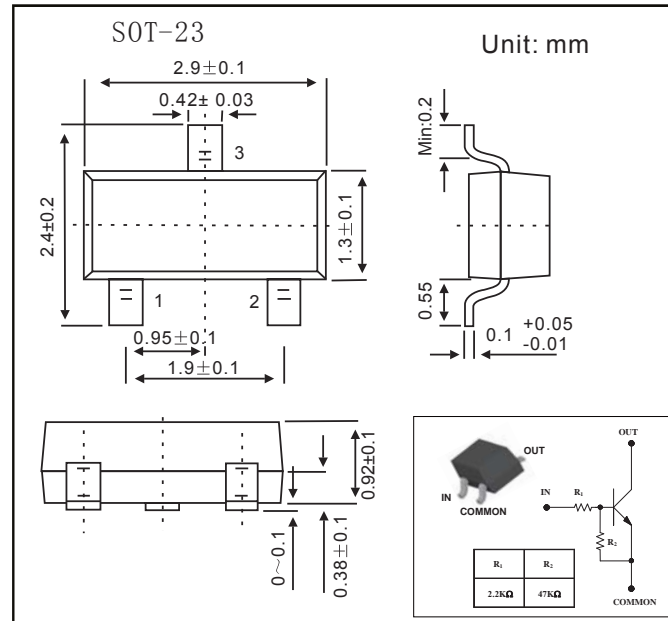
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- High packing density
- PNP Silicon Transistor

### Descriptions

- Switching application
- Interface circuit and driver circuit application

### MECHANICAL DATA

- Case: SOT-23 Small Outline Plastic Package
- Polarity: Color band denotes cathode end
- Mounting Position: Any



### ABSOLUTE MAXIMUM RATINGS

@ 25°C Ambient Temperature (unless otherwise noted)

Characteristic	Symbol	Rating	Unit
Output voltage	$V_O$	-50	V
Input voltage	$V_I$	-15, 5	V
Output current	$I_O$	-100	mA
Power dissipation	$P_D$	200	mW
Junction temperature	$T_J$	150	°C
Storage temperature range	$T_{stg}$	-55 ~ 150	°C

### Electrical Specification ( $T_A=25^\circ\text{C}$ unless otherwise specified)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Output cut-off current	$I_{O(OFF)}$	$V_O=-50V, V_I=0$	-	-	-500	nA
DC current gain	$G_I$	$V_O=-5V, I_O=-10mA$	80	200	-	-
Output voltage	$V_{O(ON)}$	$I_O=-10mA, I_I=-0.5mA$	-	-0.1	-0.3	V
Input voltage (ON)	$V_{I(ON)}$	$V_O=-0.2V, I_O=-5mA$	-	-	-1.1	V
Input voltage (OFF)	$V_{I(OFF)}$	$V_O=-5V, I_O=-0.1mA$	-0.5	-	-	V
Transition frequency	$f_T^*$	$V_O=-10V, I_O=-5mA, f=1MHz$	-	200	-	MHz
Input current	$I_I$	$V_I=-5V, I_O=0$	-	-	-3.6	mA
Input resistor (Input to base)	$R_1$	-	1.54	2.2	2.86	K $\Omega$
Input resistor (Base to common)	$R_2$	-	33	47	61	K $\Omega$

\* : Characteristic of transistor only

### Ordering Information

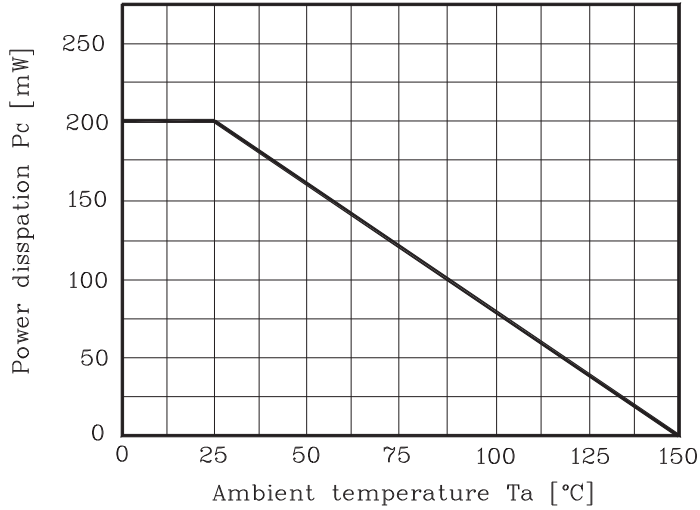
Type NO.	Marking	Package Code
SRA2205S	RA5 □ ① ②	SOT-23

① Device Code ② Year&Week Code

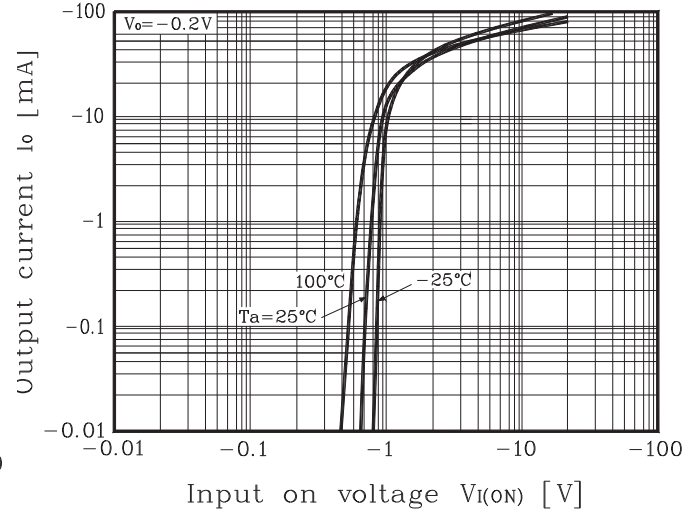
# RATINGS AND CHARACTERISTIC CURVES

## ■ Typical Characteristics

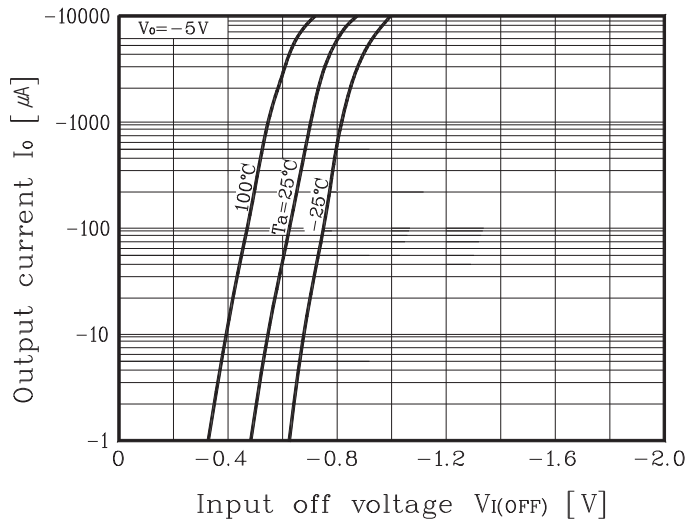
**Fig. 1  $P_c - T_a$**



**Fig. 2  $I_o - V_{I(ON)}$**



**Fig. 3  $I_o - V_{I(OFF)}$**



**Fig. 4  $G_I - I_o$**

